

BCT2211

Low Power, Low Dropout, RF-Linear Regulators

GENERAL DESCRIPTION

The BCT2211 series low-power, low-dropout, CMOS linear voltage regulators operate from a 1.6V to 5.5V input voltage and deliver up to 500mA output current. They are the perfect choice for low voltage, low power applications. A low ground current makes this part attractive for battery operated power systems. The BCT2211 series also offer low dropout voltage to prolong battery life in portable electronics. Systems requiring a quiet voltage source, such as RF applications, will benefit from the BCT2211 series low output noise and high PSRR.

Other features include a 10nA logic-controlled shutdown mode, short current limit and thermal shutdown protection.

The BCT2211 has auto-discharge function to quickly discharge VOUT in the disable status.

The BCT2211 is available in Green SOT23-5, SC70-5, packages. It operates over an ambient temperature range of -40 $^{\circ}$ C to +85 $^{\circ}$ C.

FEATURES

- Low Dropout Voltage
- Thermal Overload Protection
- Built-In Fold Back Protection Circuit
- 20µA Low Supply Current
- 10nA Logic-Controlled Shutdown
- 1.6V to 5.5V Input Voltage Range
- Fixed Outputs of 1.2V, 1.8V, 2.8V, 3.0V, and 3.3V
- Adjustable Output from 0.8V to 5.0V
- Short Auto-Discharge Function
- 500mA Output Current
- High Output Voltage Accuracy
- Quick Start-Up Time
- -40°C to +85°C Operating Temperature Range Available in Green SOT23-5, SC70-5, Packages.

APPLICATIONS

Cellular Telephones

Cordless Telephones

PCMCIA Cards

Modems

MP3 Player

Hand-Held Instruments

Palmtop Computers

Electronic Planners

Portable/Battery-Powered Equipment



ORDERING INFORMATION

Order Number	V _{OUT} (V)	Package Type	Temperature Range	Marking	QTY/Reel
BCT2211EUK12-TR	1.2	SOT23-5	-40°C to +85°C	W2XX	3000
BCT2211EUK18-TR	1.8	SOT23-5	-40°C to +85°C	W8XX	3000
BCT2211EUK28-TR	2.8	SOT23-5	-40°C to +85°C	w8xx	3000
BCT2211EUK30-TR	3.0	SOT23-5	-40°C to +85°C	W0XX	3000
BCT2211EUK33-TR	3.3	SOT23-5	-40°C to +85°C	W3XX	3000
BCT2211EUKAJ-TR	ADJ	SOT23-5	-40°C to +85°C	JJXX	3000
BCT2211EXK12-TR	1.2	SC70-5	-40°C to +85°C	U2XX	3000
BCT2211EXK18-TR	1.8	SC70-5	-40°C to +85°C	U8XX	3000
BCT2211EXK28-TR	2.8	SC70-5	-40°C to +85°C	U8XX	3000
BCT2211EXK30-TR	3.0	SC70-5	-40°C to +85°C	U0XX	3000
BCT2211EXK33-TR	3.3	SC70-5	-40°C to +85°C	U3XX	3000
BCT2211EXKAJ-TR	ADJ	SC70-5	-40°C to +85°C	JJXX	3000

Note:

"XX" in Marking will be appeared as the batch code.



ABSOLUTE MAXIMUM RATINGS

IN to GND	0.3V to 6.0V
Output Short-Circuit Duration	Infinite
EN to GND	0.3V to 6.0V
OUT,BP/FB to GND	0.3V to (VIN +0.3V)
Power Dissipation, $P_D@T_A=25^{\circ}C$	
SOT23-5	0.48W
SC70-5	0.38W
Package Thermal Resistance	
SOT23-5, θ _{JA}	260°C/W
SC70-5, θ _{JA}	330°C/W
Junction Temperature	150℃
Storage Temperature Range	65℃ to 150℃
Lead Temperature (Soldering, 10 se	c)260°C
ESD Susceptibility	
HBM	4000V
MM	400V

RECOMMENDED OPERATING CONDITIONS

Operating Voltage Range1.6	V to 5.5V
Operating Temperature Range40°C	to +85℃

OVERSTRESS CAUTION

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD SENSITIVITY CAUTION

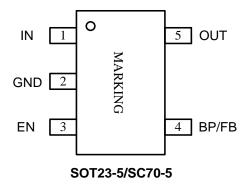
This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. Broadchip recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

DISCLAIMER

Broadchip reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time. Please contact Broadchip sales office to get the latest datasheet.



PIN CONFIGURATION (TOP VIEW)



PIN DESCRIPTION

PIN	NAME	FUNCTION
1	IN	Regulator Input. Supply voltage can range from 1.6V to 5.5V. Bypass with a 1µF capacitor to GND.
2	GND	Ground.
3	EN	Enable Pin. This pin has an internal pull-down resistor. A logic low reduces the supply current to less than 1µA.Connect to IN for normal operation.
4	BP	Reference-Noise Bypass Pin (fixed voltage version only). Bypass with a low-leakage 0.01µF ceramic capacitor for reduced noise at the output. The capacitor is recommended to be placed very close to the pin for high PSRR.
	FB	Adjustable Voltage Version Only. This is used to set the output voltage of the device.
5	OUT	Regulator Output.



ELECTRICAL CHARACTERISTICS

 $(V_{IN} = V_{OUT(NOMINAL)} + 0.5V \text{ or } 1.6V, \text{ whichever is greater, } Full = -40\,^{\circ}\text{C} \text{ to } +85\,^{\circ}\text{C}, \text{ unless otherwise noted.})$

PARAMETER	SYMBOL	CONDITIONS		TEMP	MIN	TYP	MAX	UNITS	
Input Voltage	V _{IN}			+25℃	1.6		5.5	V	
Output Voltage Accuracy		I _{OUT} = 0.1mA		+25℃	-2.5		+2.5	%	
Feedback Voltage	V_{FB}	I _{OUT} = 0.1mA, BCT2211	I-ADJ		+25℃	0.78	0.8	0.82	V
Maximum Output Current (1)					+25℃	500			mA
Current Limit	I _{LIM}				+25℃	560	800		mA
Supply Pin Current	IQ	No Load, V _{EN} = V _{IN}			+25℃		20	26	μΑ
			1.2V	≤ V _{OUT} < 1.8V	+25℃		945	1280	
2	.,		1.8V	≤ V _{OUT} < 2.5V	+25℃	+25℃ 510 670	670	1	
Dropout Voltage (2)	V_{DROP}	I _{OUT} = 500mA	2.5V	≤ V _{OUT} < 3.0V	+25℃		345	450	mV
			3.0V	≤ V _{OUT} < 3.6V	+25℃		305	400	1
	۸\/	$V_{IN} = 1.6V$ or $(V_{OUT} +$	1.8V	≤ V _{OUT} ≤ 3.3V	+25℃		0.01	1 0.06	
Line Regulation	$\frac{\Delta V_{OUT}}{\Delta V_{IN} \times V_{OUT}}$	0.5V) to 5.5V, I _{OUT} = 1mA	V_{OUT} < 1.8V or V_{OUT} > 3.3V		+25℃		0.01	0.1	%/V
Load Regulation	ΔV_{OUT}	I _{OUT} = 0.1mA to 500mA		+25℃		12	40	mV	
Short Current Limit	I _{SHORT}	V _{OUT} = 0V	V _{OUT} = 0V		+25℃		320		mA
		$C_{BP} = 0\mu F$, $I_{OUT} = 30mA$	λ,	f = 217Hz	+25℃		80		
Power Supply Rejection Ratio	PSRR	$C_{OUT} = 1\mu F, V_{IN} = V_{OUT}$ $\Delta V_{RIPPLE} = 0.2 V_{P-P}$	+ 1V,	f = 1kHz +25°C 70 f = 217Hz +25°C 82	70		- dB		
Tower Supply Rejection Ratio	TORK	$C_{BP} = 0.01 \mu F, I_{OUT} = 30$			82				
		$C_{OUT} = 1\mu F$, $V_{IN} = V_{OUT}$ $\Delta V_{RIPPLE} = 0.2 V_{P-P}$	+ 1V,	f = 1kHz	xHz +25℃		70		
Output Voltage Noise		$C_{BP} = 0\mu F$, $f = 10Hz$ to		I _{OUT} = 0mA	+25℃		100		
		100kHz, $C_{OUT} = 1\mu F, V_{OUT} = 1.8$	V	I _{OUT} = 30mA	+25℃		200		
	e n	$C_{BP} = 0.01 \mu F, f = 10 Hz$		I _{OUT} = 0mA	A +25°C 30		μVRMS		
		100kHz, $C_{OUT} = 1\mu F$, $V_{OUT} = 1.8V$		I _{OUT} = 30mA	+25℃		75		
Output Voltage Temperature Coefficient (3)	$\frac{\Delta V_{OUT}}{\Delta T_{A} \times V_{OUT}}$	I _{OUT} = 0.1mA		Full		30		ppm/℃	



ELECTRICAL CHARACTERISTICS

 $(V_{IN} = V_{OUT(NOMINAL)} + 0.5V)$ or 1.6V, whichever is greater, Full = -40°C to +85°C, unless otherwise noted.)

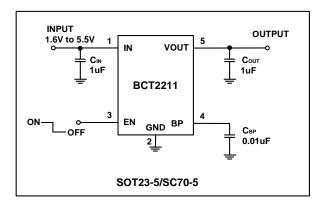
PARAMETER	SYMBOL	CONDITIONS	ТЕМР	MIN	TYP	MAX	UNITS	
SHUTDOWN								
ENLIGHT Through ald	V_{IH}	- V _{IN} = 1.6V to 5.5V	Full	1.5			v	
EN Input Threshold	V _{IL}		Full			0.4	V	
CN Input Bigg Current	I _{BH}	V _{EN} = 5.5V	Full		0.8	2		
EN Input Bias Current	I _{BL}	V _{EN} = 0V	Full		0.01	1	μΑ	
Shutdown Supply Current	I _{SHDN}	V _{EN} = 0V	Full		0.01	1	μΑ	
Start-Up Time (4)	t _{STR}	$C_{OUT} = 1\mu F$, No Load, $C_{BP} = 0\mu F$	+25℃		30		μs	
R _{ON} of Discharge MOSFET		$V_{IN} = 4.0V, V_{EN} = 0V$	+25℃		50		Ω	
THERMAL PROTECTION								
Thermal Shutdown	T _{SHDN}				140		$^{\circ}$	
Temperature	· OFIDIN				. 10			
Thermal Shutdown Hysteresis	ΔT_{SHDN}				15		$^{\circ}$	

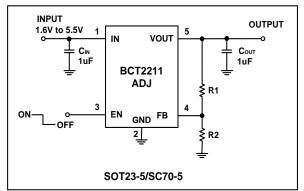
NOTES:

- Maximum output current is affected by the PCB layout, size of metal trace, the thermal conduction path between metal layers, ambient temperature and the other environment factors of system. Attention should be paid to the dropout voltage when VIN
 VOUT + VDROP.
- 2. The dropout voltage is defined as VIN VOUT, when VOUT is 100mV below the value of VOUT.
- 3. Output voltage temperature coefficient is defined as the worst-case voltage change divided by the total temperature range.
- 4. Time needed for VOUT to reach 90% of final value.



TYPICAL APPLICATION CIRCUIT





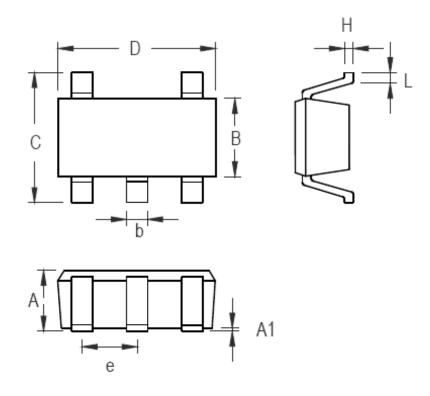
NOTES: Choose R2 = $160k\Omega$ to maintain a $5\mu A$ minimum load. Calculate the value for R1 using the following equation:

$$\mathbf{R}_1 = \mathbf{R}_2 \times \left(\frac{\mathbf{V}_{\text{OUT}}}{0.8\mathbf{V}} - 1\right)$$



PACKAGE OUTLINE DIMENSIONS

SOT23-5

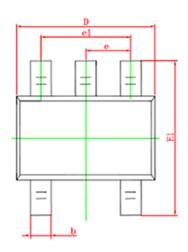


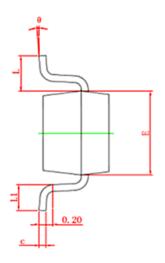
Symbol	Dimensions In Millimeters				
Symbol	Min	Max			
Α	1.05	1.15			
A1	0.03	0.15			
В	1.5	1.7			
b	0.28	0.45			
С	2.75	3.05			
D	2.82	3.02			
е	0.95(BSC)				
Н	0.12	0.23			
L	0.35	0.55			

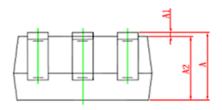
SOT23-5 Surface Mount Package



SC70-5







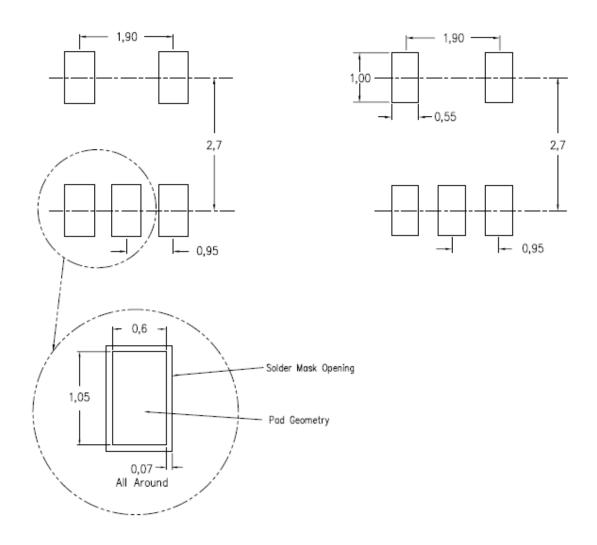
Symbol	Dimensions In Millimeters				
Symbol	Min.	Max.			
Α	0.900	1.100			
A1	0.000	0.100			
A2	0.900	1.000			
b	0.150	0.350			
С	0.110	0.175			
D	2.000	2.200			
E	1.150	1.350			
E1	2.150	2.450			
е	0.650 TYP.				
e1	1.200	1.400			
L	0.525 REF.				
L1	0.260	0.460			
θ	0°	8°			

SC70-5 Surface Mount Package



LAND PATTERN DATA

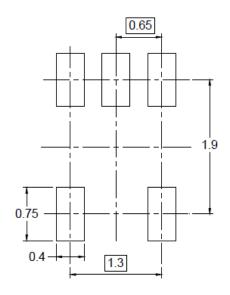
SOT23-5



RECOMMENDED PCB LAYOUT PATTERN (Unit: mm)



SC70-5



RECOMMENDED PCB LAYOUT PATTERN (Unit: mm)